

TECHNICAL DATA
DATA SHEET 4234, REV. -

HERMETIC SILICON CARBIDE RECTIFIER

DESCRIPTION: A 300-VOLT, 20 AMP, POWER SILICON CARBIDE RECTIFIER IN A HERMETIC TO-257 PACKAGE AVAILABLE SCREENED TO ANY REQUIRED LEVEL

FEATURES:

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR
- **High Temperature Option** - Maximum operation & storage temperature can be increased to 250°C; use part number prefix as SHDT
- **High Frequency Option** - Non-magnetic Glidcop leads are available for improved performance at high frequency; use part number prefix SHDG
- **Ceramic Seal Option** – For ceramic seals use part number prefix SHDC

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	300	Volts
MAXIMUM DC OUTPUT CURRENT (With T _C = 65 °C, for part numbers with P and N suffixes)	I _O	20	Amps
MAXIMUM DC OUTPUT CURRENT (With T _C = 65 °C, for part numbers with Single and D suffixes)	I _O	10	Amps
MAXIMUM REPETITIVE FORWARD SURGE CURRENT PER LEG (t = 8.3ms, Sine) per leg, T _C = 25 °C	I _{FRM}	40	Amps
MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG (t = 10μs, Pulse) per leg, T _C = 25 °C	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V) per leg	C _T	660	pF
MAXIMUM POWER DISSIPATION, T _C = 25 °C	P _d	40	W
MAXIMUM THERMAL RESISTANCE, Junction to Case (PER DUAL PACKAGE For Common Cathode/Anode Configurations)	R _{θJC}	4.8	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top, Tstg	-55 to +175	°C

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TYP	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 5 A PER LEG) V _f	T _J = 25 °C T _J = 175 °C	0.90 1.00	1.20 1.30 Volts
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 10 A PER LEG) V _f	T _J = 25 °C T _J = 175 °C	1.20 1.40	1.40 1.80 Volts
MAXIMUM REVERSE CURRENT (I _r @ 300V PIV PER LEG)	T _J = 25 °C T _J = 175 °C	0.05 1.00	0.25 2.00 mA
TOTAL CAPACITIVE CHARGE (V _R =300V I _F =10A di/dt=500A/μs T _J =25°C) Q _C per leg		11.5	N/A nC

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Figure 1. Forward Characteristics

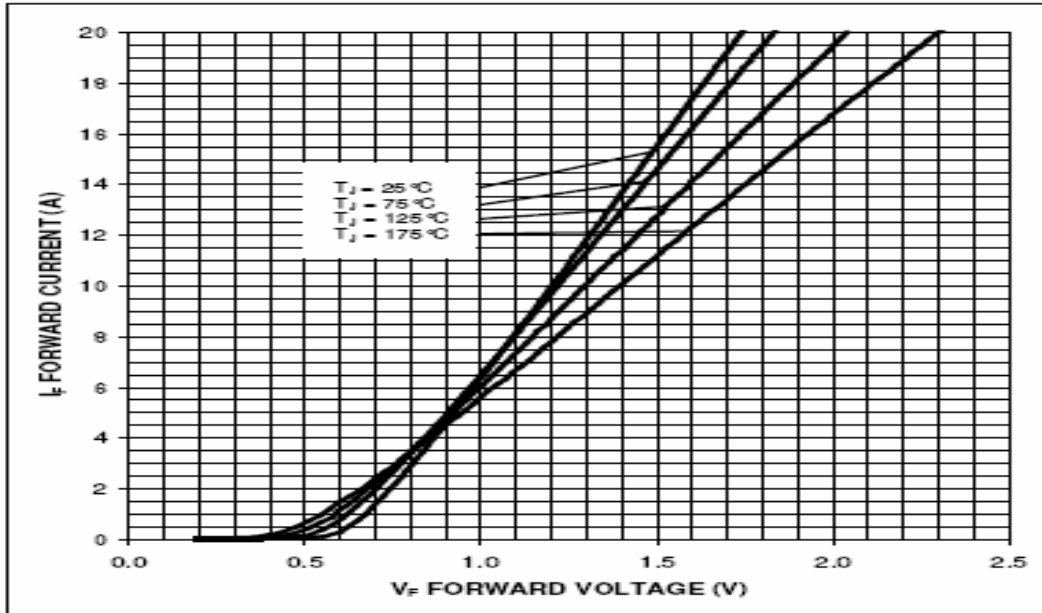
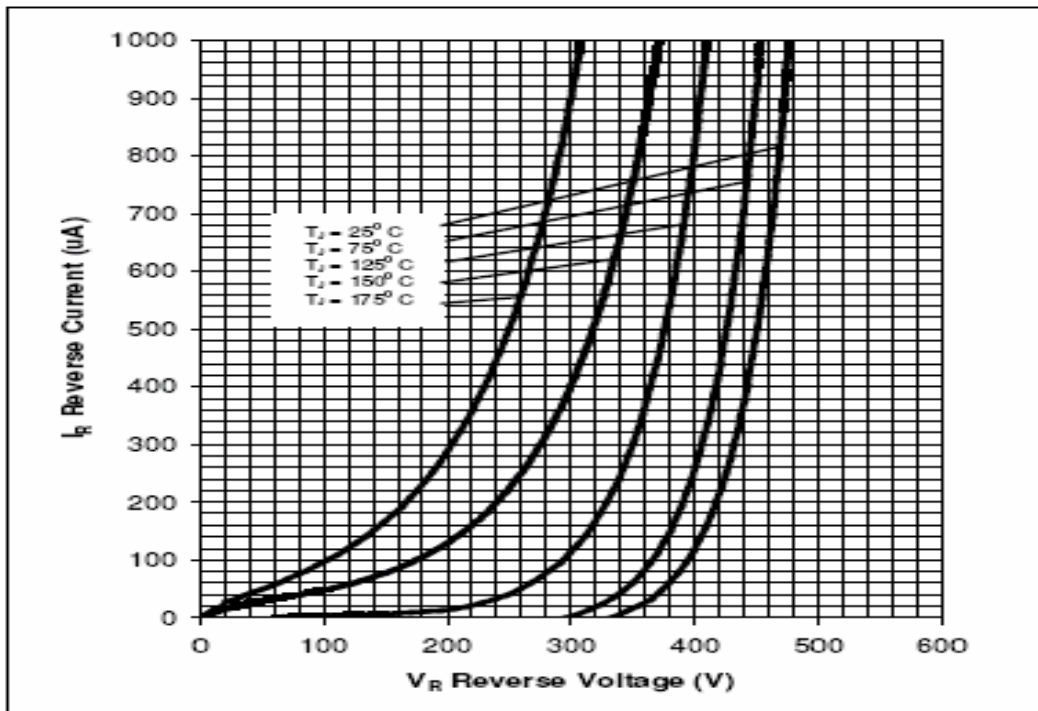


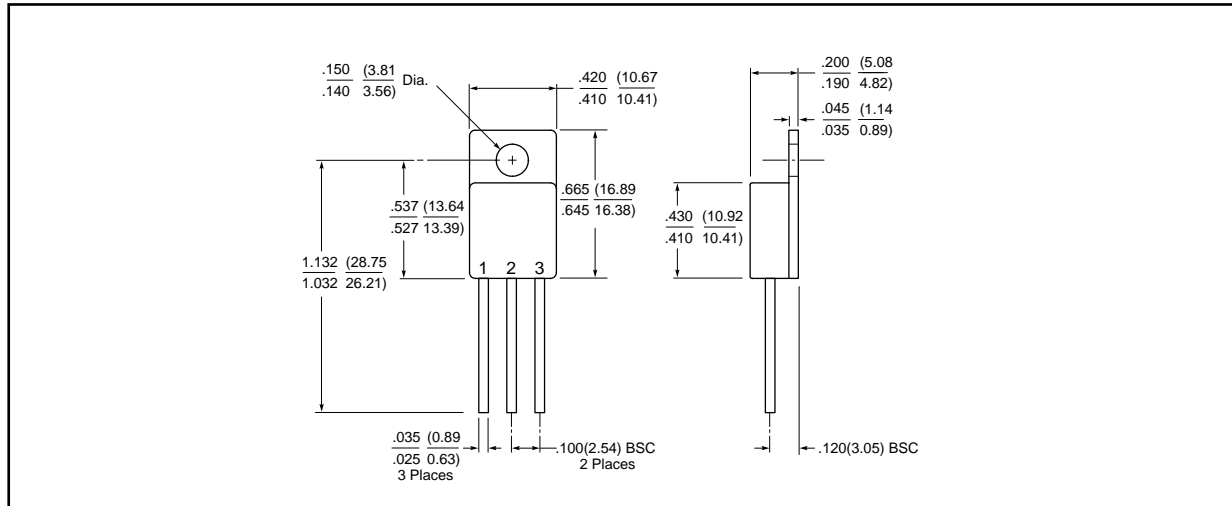
Figure 2. Reverse Characteristics



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MECHANICAL DIMENSIONS

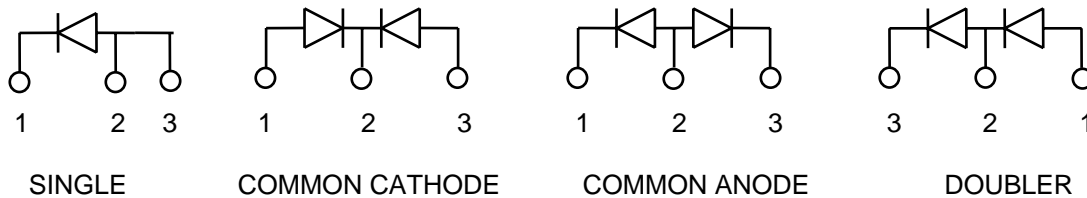
TO-257



PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER/COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER/COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER/DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

SCHEMATIC



Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited.

Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.

TECHNICAL DATA

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